Unit: mm

ANODE ANODE CATHODE

TOSHIBA Diode Silicon Epitaxial Schottky Barrier Type

# **1SS392**

### **High Speed Switching Application**

• Low forward voltage  $: V_{F(3)} = 0.54V \text{ (typ.)}$ • Low reverse current  $: I_{R} = 5\mu\text{A (max)}$ 

• Small package : SC-59

### **Maximum Ratings (Ta = 25°C)**

Characteristic	Symbol	Rating	Unit	
Maximum (peak) reverse Voltage	$V_{RM}$	45	V	
Reverse voltage	$V_{R}$	40	V	
Maximum (peak) forward current	I <sub>FM</sub>	300 *	mA	
Average forward current	Io	100 *	mA	
Surge current (10ms)	I <sub>FSM</sub>	1 *	Α	
Power dissipation	Р	150	mW	
Junction temperature	Tj	125	°C	
Storage temperature range	T <sub>stg</sub>	<b>-</b> 55~125	°C	
Operating temperature range	T <sub>opr</sub>	<b>−</b> 40~100	°C	

<sup>\* :</sup> Unit rating. Total rating = unit rating × 1.5

#### 1.1-0.1 1.0-0.1 1.0-0.15

O-MILIVI	
JEDEC	TO-236MOD
EIAJ	SC-59
TOSHIBA	1-3G1F

Weight: 0.012g

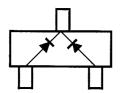
#### **Electrical Characteristics (Ta = 25°C)**

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit	
Forward voltage	V <sub>F (1)</sub>	_	I <sub>F</sub> = 1mA	_	0.28	_	V	
	V <sub>F (2)</sub>	_	I <sub>F</sub> = 10mA	_	0.36	_		
	V <sub>F (3)</sub>	_	I <sub>F</sub> = 100mA	_	0.54	0.60		
Reverse current	I <sub>R</sub>	_	V <sub>R</sub> = 40V	_	_	5	μΑ	
Total capacitance	C <sub>T</sub>	_	$V_R = 0$ , $f = 1MH_Z$	1	18	25	pF	

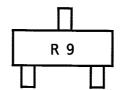
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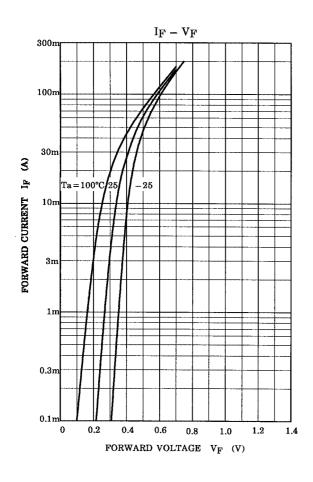
2001-06-07

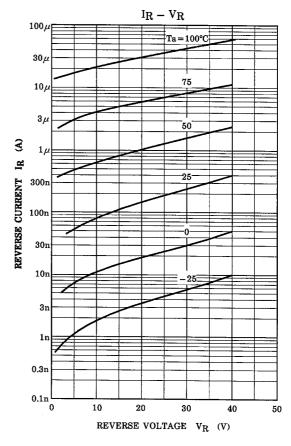
## **Equivalent Circuit (Top View)**

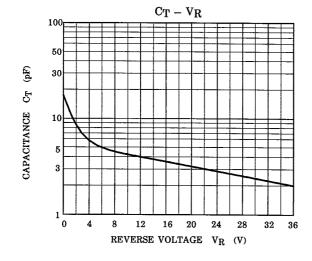


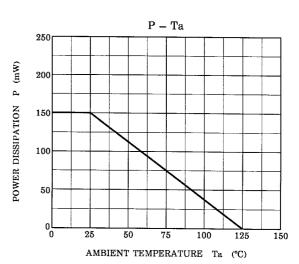
### Marking











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